Technical Data Sheet

Features

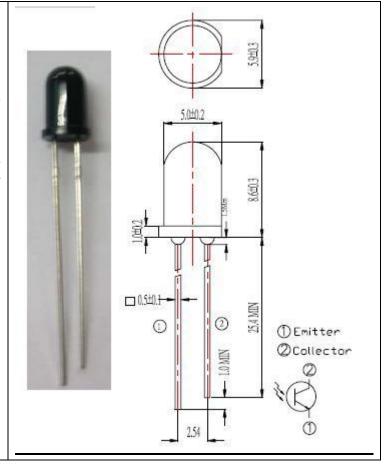
- Fast response tine
- High photo sensitivity
- Pb free
- This product itself will remain within RoHS conpliant version.

Descriptions

• YG1006 is a high speed and high sensitive NPNsiicon phototransistor in a standard5mm package.

Due to its black epoxy the device is sensitive to infrared radiation.

Package Dimensions



Note: 1. All dimensions are in millimeters

2. Tolerances unless dimensions ± 0.25 mm

Absoulute Maximum Ratings (Ta=25℃)

Parameter	Symbol	rating	units
Collector-Emitter Voltage	Vceo	30	V
Emitter-Collector-Voltage	V _{ECO}	5	V
Collector Current	Ic	20	mA
Operating Temperature	Topr	-25~+85℃	${\mathbb C}$
Storage Temperature	Tstg	-40+85℃	${\mathbb C}$
Lead Soldering Temperature	Tsol	260	${\mathbb C}$
Power Dissipation at (or	Рс	75	mW
below) 25℃ FreeAir			
Temperature			

Electro-Opticai Characteristcs (Ta=25°C)

Parameter Symbol Condition Min. Тур. Max. Units V Collector-Emitter BVCEO 30 Ic=100µA Breakdown VoItage $Ee=0mW/C m^2$ $IE=100\mu A$ **Emitter-Collector** BVECO 5 V Ee=OmW/C m² Saturation VoItage Collector-Emitter Ic=2mA V VCE(sat) 0.4 Saturation VoItage $Ee=1mW/C m^2$ VCE=5V Rise Time 15 tf μS Ic=1mA Fall Time 15 tf --- $RL=1000\Omega$ Collector Dark ICEO $Ee=0mW/C m^2$ 100 nA----Current $V_{CE}=20V$ On State Collector $Ee=1mW/Cm^2$ 7.07 Ic(on) 1.77 mA Current VCE=5V Wavelength of Peak λР 940 nm Sensitivity 760-1100 Rang of Spectral nm Bandwidth λ0.5 Parameter Max Unit **Test Condition** Symbol Min VCE=5V Ic(on) $Ee=1mW/Cm^2$ J 1.77 3.61 mAK 5.07 2.67

Rankings

Typical Electro-Optical Characteristics Curves

7.07

4.18

L

Fig.1Collector Power Dissipation vs.

Ambient Temperature

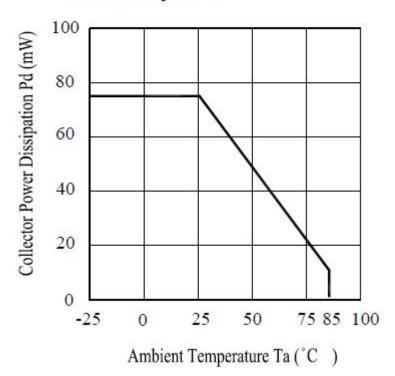


Fig.2 Spectral Sensitivity

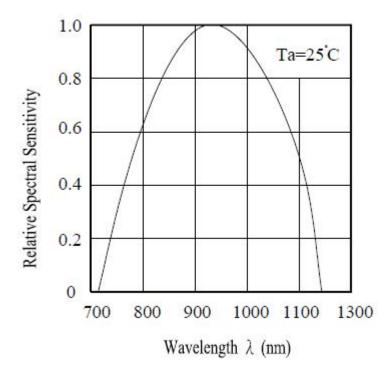


Fig.3 Relative Collector Current vs.

Ambient Temperature

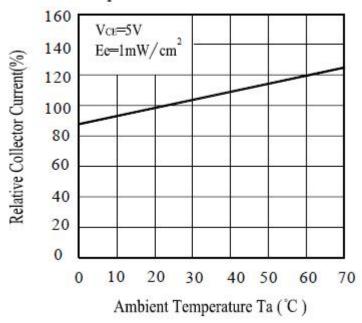
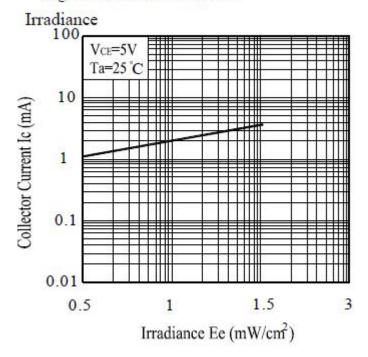


Fig.4 Collector Current vs.



Typical Electro-Optical Characteristecs

Fig.5 Collector Dark Current vs.

Ambient Temperature

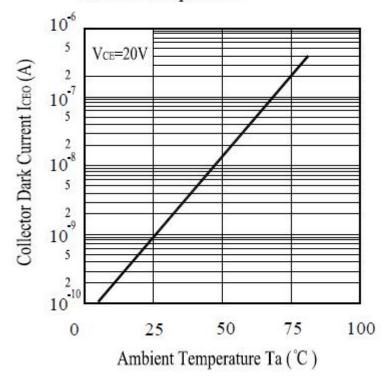
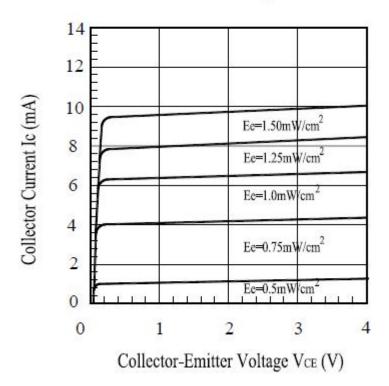


Fig.6 Collector Current vs.

Collector-Emitter Voltage



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level: 90%

LTPD: 10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP. : 260°C±5°C	10secs	22pcs		0/1
2	Temperature Cycle	H:+100°C	300Cycles	22pes	$I_{C(ON)} \leq L \times 0.8$	0/1
3	Thermal Shock	H:+100°C	300Cycles	22pcs	L: the initial test value	0/1
4	High Temperature Storage	TEMP. : +100℃	1000hrs	22pcs		0/1
5	Low Temperature Storage	TEMP. : -40°C	1000hrs	22pcs		0/1
6	DC Operating Life	V _{CE} =5V	1000hrs	22pes		0/1
7	High Temperature/ High Humidity	85℃ / 85% R.H	1000hrs	22pcs		0/1